

DECLARATION OF SOLE INVENTOR FOR PATENT APPLICATION

As the below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled: "Capacitor Constructions Comprising Perovskite-type Dielectric Materials, and Methods of Forming Capacitor Constructions Comprising Perovskite-type Dielectric Materials", the specification of which is attached hereto.

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims.

I acknowledge the duty to disclose information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations § 1.56.

PRIOR FOREIGN APPLICATIONS:

I hereby state that no applications for foreign patents or inventor's certificates have been filed prior to the date of execution of this declaration.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such

willful false statement may jeopardize the validity of the application or any patent issued therefrom.

* * * * *

Full name of sole inventor:

Cem Basceri

Inventor's Signature:

Cem Basceri

Date:

8-9-01

Residence:

Boise, Idaho

Citizenship:

Turkey

Post Office Address:

**314 E. Iowa Drive
Boise, ID 83706**

11/27/01 10:00 AM

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. Filed Herewith
 Filing Date Filed Herewith
 Inventor Cem Basceri
 Assignee Micron Technology, Inc.
 Attorney's Docket No. MI22-1731
 Title: "Capacitor Constructions Comprising Perovskite-Type Dielectric Materials,
 and Methods of Forming Capacitor Constructions Comprising
 Perovskite-Type Dielectric Materials"

**POWER OF ATTORNEY BY ASSIGNEE AND
 CERTIFICATE BY ASSIGNEE UNDER 37 CFR § 3.73(b)**

To: Assistant Commissioner for Patents
 Washington, D.C. 20231

Sir:

MICRON TECHNOLOGY, INC., the Assignee of the entire right, title and interest in the above-identified patent application by assignment attached hereto, hereby appoints the attorneys and agents of the firm of WELLS, ST. JOHN, ROBERTS, GREGORY & MATKIN P.S., listed as follows:

David P. Roberts	Reg. No. 23,032
Randy A. Gregory	Reg. No. 30,386
Mark S. Matkin	Reg. No. 32,268
James L. Price	Reg. No. 27,376
Deepak Malhotra	Reg. No. 33,560
Mark W. Hendricksen	Reg. No. 32,356
David G. Latwesen	Reg. No. 38,533
George G. Grigel	Reg. No. 31,166
Keith D. Grzelak	Reg. No. 37,144
James D. Shaurette	Reg. No. 39,833
Frederick M. Fliegel	Reg. No. 36,138
Donald Brent Kenady	Reg. No. 40,045
James E. Lake	Reg. No. 44,854
Bernard Berman	Reg. No. 37,279
Jennifer J. Taylor, Ph.D.	Reg. No. P 48,711

and also attorneys Michael L. Lynch (Reg. No. 30,871) and Charles B. Brantley II (Reg. No. 38,086) of Micron Technology, Inc., as its attorneys with full power of substitution to prosecute this application and transact all business in the Patent and Trademark Office connected therewith.

The Assignee certifies that the above-identified Assignment has been reviewed and to the best of Assignee's knowledge and belief, title is in the Assignee, and a copy of the Assignment is submitted herewith.

Please direct all correspondence regarding this application to:

Customer No. 021567
Wells, St. John, Roberts, Gregory & Matkin P.S.
Attn: David G. Latwesen, Ph.D.
601 West First Avenue, Suite 1300
Spokane, WA 99201-3828

Telephone: (509) 624-4276
Facsimile: (509) 838-3424

MICRON TECHNOLOGY, INC.

Dated: 8-14-01

By: [Signature]

Name: Michael L. Lynch, Esq.
Title: Chief Patent Counsel

Attachment: Copy of Assignment; Copy of Board of Directors' Resolution